

II. Schottky Rectifier

0.2A Surface Mount Schottky Rectifier BAT42W / BAT43W

(Package: SOD-123)

<p>FEATURES</p> <ul style="list-style-type: none"> • Low forward voltage drop • Guard ring construction for transient protection • High conductance <p>MECHANICAL DATA</p> <ul style="list-style-type: none"> • Case : Molded plastic body • Terminals : Plated leads solderable per MIL-STD-750, Method 2026 • Polarity : Polarity symbols marked on case • Marking : BAT42W : S7 BAT43W : S8 	<p>Case: SOD-123 Dimensions in millimetres (inches)</p>
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MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Limits	Unit
Non-Repetitive Peak reverse voltage	V_{RM}		
Working peak DC Reverse Voltage	V_{RWM}	30	V
RMS Reverse Voltage	$V_{R(RMS)}$	21	V
Forward continuous Current	I_F	200	mA
Repetitive peak Forward Current	I_{FRM}	500	mA
Forward Surge Current	I_{FSM}	4.0	A
Power Dissipation	P_d	200	mW
Thermal resistance, junction to ambient air	$R_{\theta jA}$	625	$^\circ\text{C}/\text{W}$
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to +125	$^\circ\text{C}$

F.E.C. Semiconductor

Ratings of BAT42W / BAT43W

ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	$V_{(\text{BR})R}$	$I_R=100\mu\text{A}$	30			V
Forward voltage ALL types BAT42W BAT42W BAT43W BAT43W	V_F	$I_F=200\text{mA}$			1.0	V
	V_F	$I_F=10\text{mA}$			0.4	V
	V_F	$I_F=50\text{mA}$			0.65	V
	V_F	$I_F=2\text{mA}$	0.26		0.33	V
	V_F	$I_F=15\text{mA}$			0.45	V
Reverse current	I_R	$V_R=25\text{V}$			0.5	μA
Reverse recovery time	t_{rr}	$I_F=I_R=10\text{mA}$ $I_{rr}=0.1*I_R$ $R_L=100\Omega$			5.0	ns
Capacitance between terminals	C_T	$V_R=1\text{V}, f=1\text{MHz}$			10	pF
Rectification efficiency	η_V	$R_L=15\Omega, C_L=300\text{pF},$ $f=45\text{MHz}$	80			%